

CORRECTION

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rsc.li/materials-cCorrection: Chlorine-doped SnO₂ hydrophobic surfaces for large grain perovskite solar cellsWenxiao Gong,^a Heng Guo,^{a,b} Haiyan Zhang,^a Jian Yang,^a Haiyuan Chen,^a Liping Wang,^a Feng Hao^a and Xiaobin Niu^{a*}Correction for 'Chlorine-doped SnO₂ hydrophobic surfaces for large grain perovskite solar cells' by Wenxiao Gong et al., *J. Mater. Chem. C*, 2020, DOI: 10.1039/d0tc00515k.

The authors regret errors in Fig. 6 in the published article (incorrect panels of data were erroneously inserted as Fig. 6d and Fig. 6e in the published version). A corrected version of Fig. 6 is provided here.

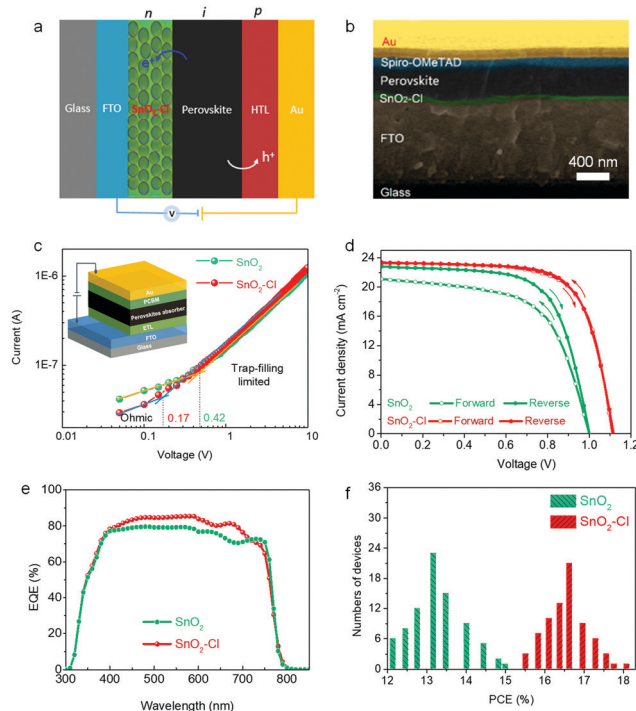


Fig. 6 (a) Illustrative schematic of the device architecture for the PSCs studied in this work. (b) The cross-sectional SEM images of devices with an SnO₂-Cl ETL. (c) Dark *J*-*V* curve of electron-only devices deposited on SnO₂ and SnO₂-Cl films. (d) *J*-*V* characteristics of devices with SnO₂ and SnO₂-Cl ETLs measured at forwarding scan (from 0 V to 1.1 V) and reverse scan (from 1.1 V to 0 V) at the scan rate 0.1 V s⁻¹. (e) External quantum efficiency (EQE) spectra of devices with SnO₂ and SnO₂-Cl ETLs. (f) Histograms of PCEs for the solar cells with SnO₂ and SnO₂-Cl as ETLs.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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